

220158US-2X DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

#2 / PRE-AMDT
A
C. Que
4/19/02

IN RE APPLICATION OF: :
MASATAKA HASEGAWA ET AL : ATTN: APPLICATION DIVISION
SERIAL NO: NEW U.S. APPLICATION :
FILED: HEREWITH :
FOR: DIAMOND SEMICONDUCTOR AND
METHOD FOR THE FABRICATION
THEREOF

PRELIMINARY AMENDMENT

ASSISTANT COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

SIR:

Prior to a first examination on the merits, please amend the above-identified
application as follows:

IN THE CLAIMS

✓
Please cancel claims 1 and 2 without prejudice.

REMARKS

Favorable consideration of this application, as presently amended, is respectfully
requested.

The present application is a divisional of copending parent U.S. application serial no.
09/621,360. In that parent application Claims 3-6 were withdrawn as directed to a non-